

Part Number: SBC23-11SURKCGKWA

Hyper Red
Green

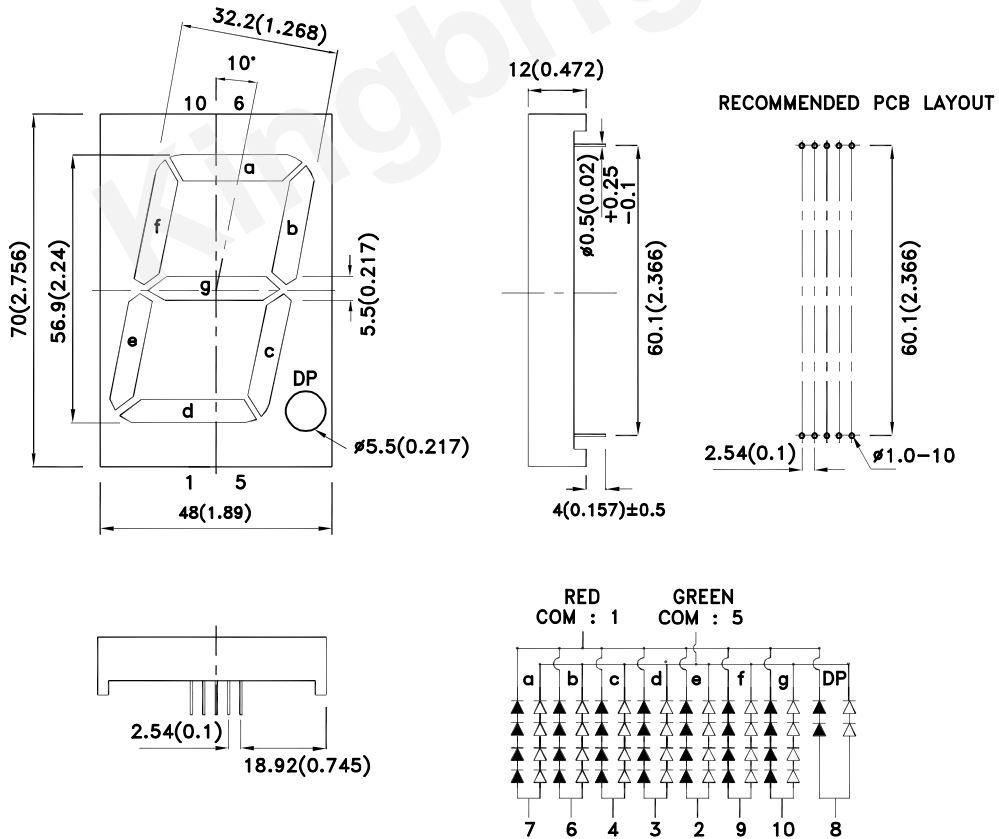
Features

- 2.3 inch digit height.
- Low current operation.
- Excellent character appearance.
- High light output.
- Easy mounting on P.C. boards or sockets.
- Multicolor available.
- Mechanically rugged.
- Standard : gray face, white segment.
- RoHS compliant.

Description

The Hyper Red source color devices are made with Al-GaInP on GaAs substrate Light Emitting Diode.
The Green source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
2. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.



Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
SBC23-11SURKCGKWA	Hyper Red (AlGaInP)	White Diffused	255000	440000	Common Cathode. Rt. Hand Decimal
			*52000	*120000	
	Green (AlGaInP)		88000	200000	
			*31000	*62000	

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

*Luminous intensity value is traceable to the CIE127-2007 compliant national standards

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Hyper Red Green	645 574		nm	I _F =20mA
λ_D [1]	Dominant Wavelength	Hyper Red Green	630 570		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Hyper Red Green	28 20		nm	I _F =20mA
C	Capacitance	Hyper Red Green	35 15		pF	V _F =0V;f=1MHz
V _F [2]	Forward Voltage (DP)	Hyper Red Green	7.8(3.9) 8.4(4.2)	10(5) 10(5)	V	I _F =20mA
I _R	Reverse Current (Per chip)	Hyper Red Green		10 (10)	uA	V _R =5V

Notes:

1.Wavelength: +/-1nm.

2.Forward Voltage: +/-0.1V.

3.Wavelength value is traceable to the CIE127-2007 compliant national standards.

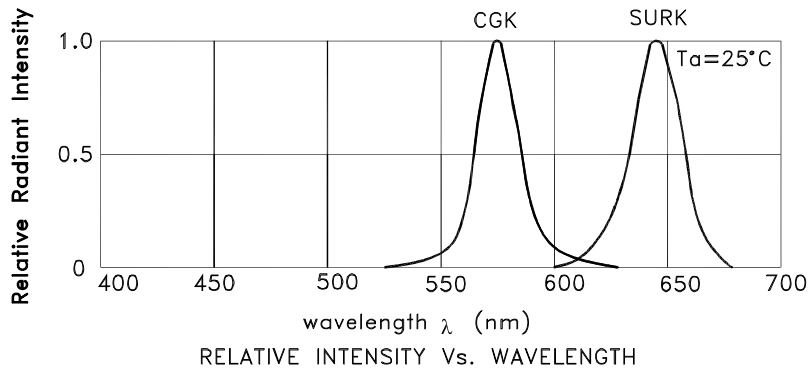
Absolute Maximum Ratings at TA=25°C

Parameter	Hyper Red	Green	Units
Power dissipation (DP)	300 (150)	300 (150)	mW
DC Forward Current	30	30	mA
Peak Forward Current [1]	185	150	mA
Reverse Voltage (Per chip)	5		V
Operating / Storage Temperature	-40°C To +85°C		
Lead Solder Temperature[2]	260°C For 3-5 Seconds		

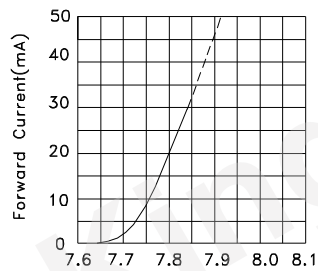
Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

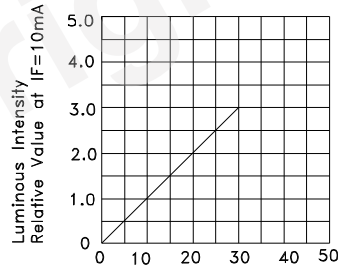
2. 2mm below package base.



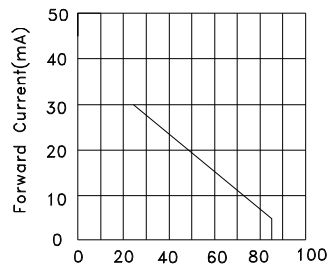
SBC23-11SURKCGKWA Hyper Red



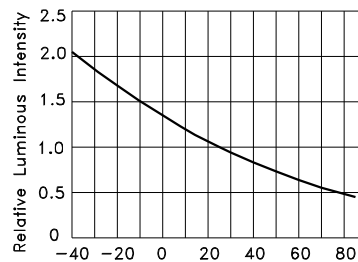
Forward Voltage(V)
FORWARD CURRENT Vs
FORWARD VOLTAGE



I_F -Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



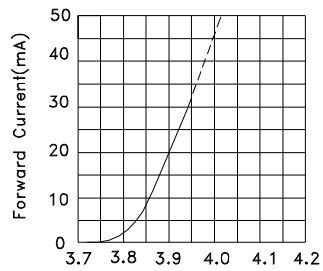
Ambient Temperature T_A ($^\circ\text{C}$)
FORWARD CURRENT
DERATING CURVE



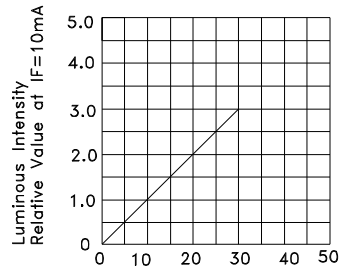
Ambient Temperature T_A ($^\circ\text{C}$)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

Kingbright

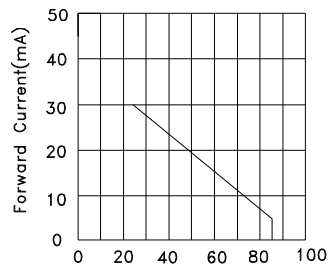
Hyper Red



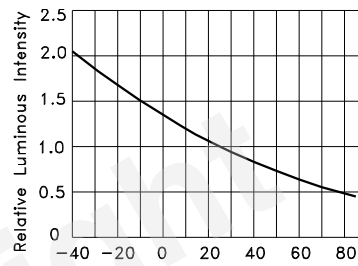
Forward Voltage(V)
FORWARD CURRENT Vs
FORWARD VOLTAGE



IF-Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT

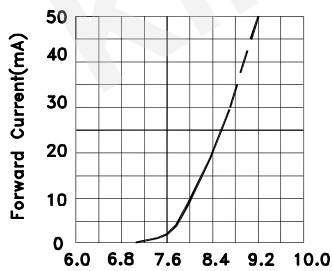


Ambient Temperature TA (°C)
FORWARD CURRENT
DERATING CURVE

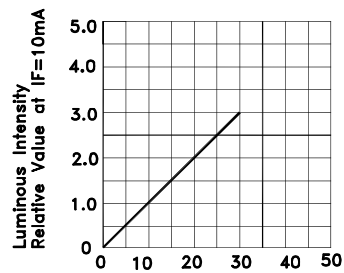


Ambient Temperature TA (°C)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

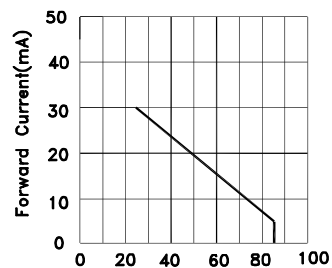
Green



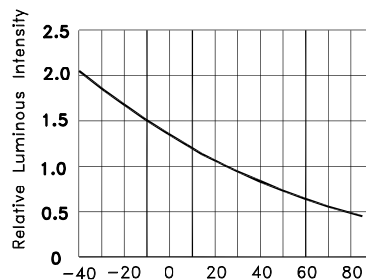
Forward Voltage(V)
FORWARD CURRENT Vs
FORWARD VOLTAGE



IF-Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT

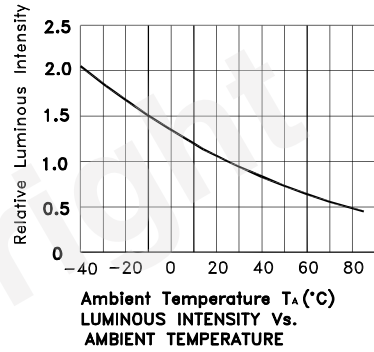
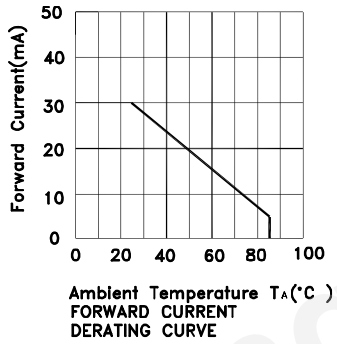
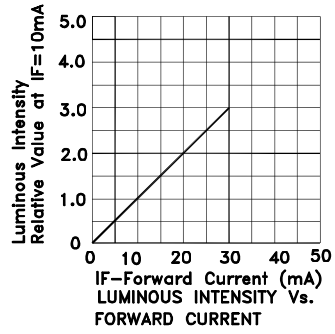
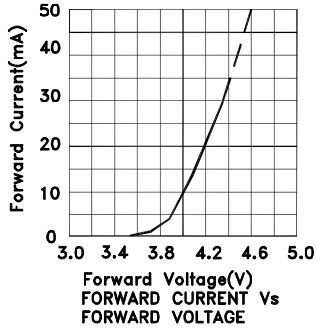


Ambient Temperature TA (°C)
FORWARD CURRENT
DERATING CURVE



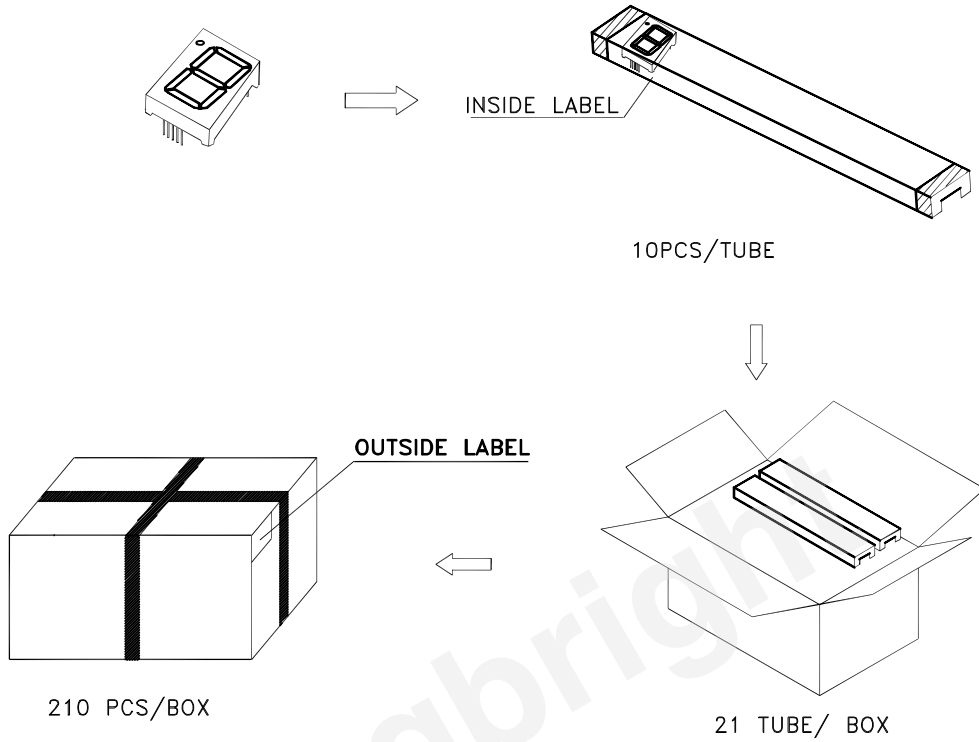
Ambient Temperature TA (°C)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

Green

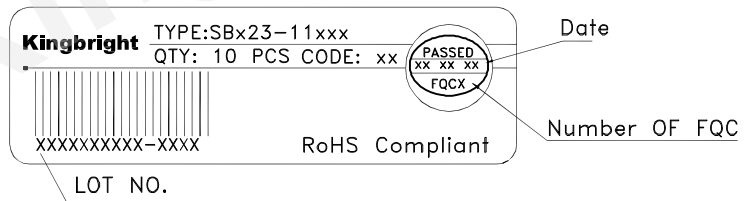


PACKING & LABEL SPECIFICATIONS

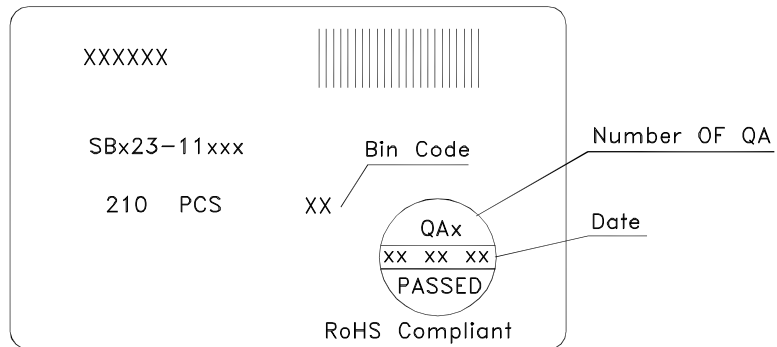
SBC23-11SURKCGKWA



Inside Label on IC-tube



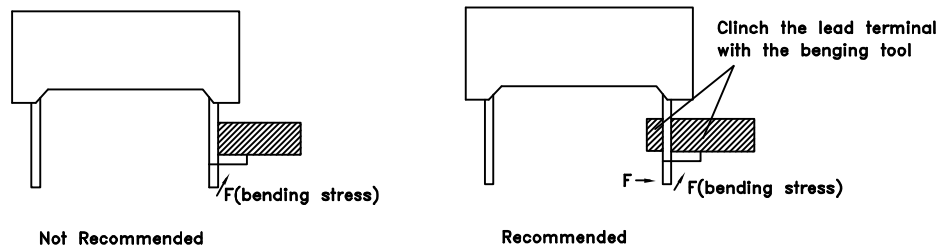
Outside Label on Box



THROUGH HOLE DISPLAY MOUNTING METHOD

Lead Forming

Do not bend the component leads by hand without proper tools.
The leads should be bent by clinching the upper part of the lead firmly such that the bending force is not exerted on the plastic body.

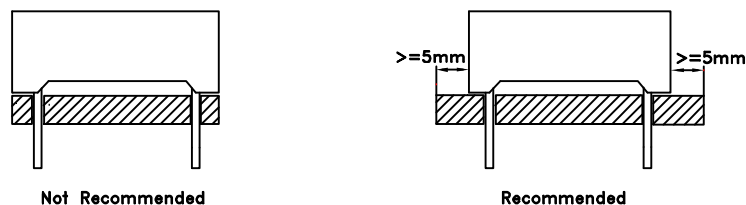


Installation

- 1.The installation process should not apply stress to the lead terminals.
- 2.When inserting for assembly, ensure the terminal pitch matches the substrate board's hole pitch to prevent spreading or pinching the lead terminals.

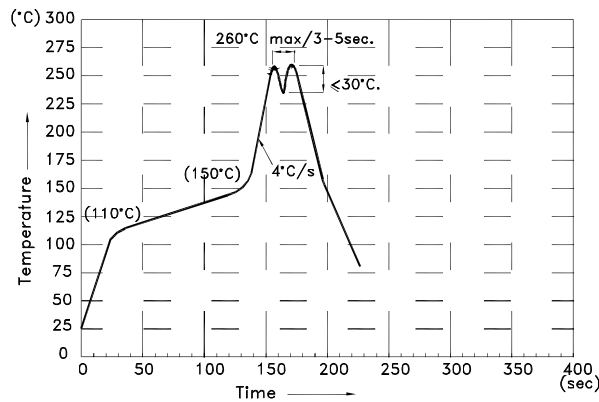


- 3.The component shall be placed at least 5mm from edge of PCB to avoid damage caused excessive heat during wave soldering.



DISPLAY SOLDERING CONDITIONS

Wave Soldering Profile For Lead-free Through-hole LED.



NOTES:

1. Recommend the wave temperature 245°C~260°C. The maximum soldering temperature should be less than 260°C.
2. Do not apply stress on epoxy resins when temperature is over 85°C.
3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
4. During wave soldering, the PCB top-surface temperature should be kept below 105°C
5. No more than once.

Soldering General Notes:

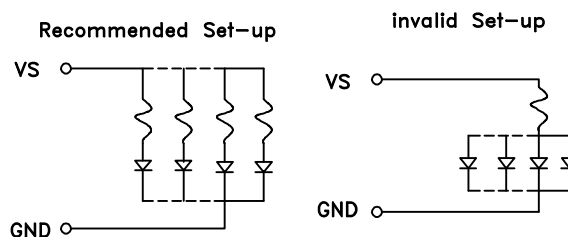
1. Through-hole displays are incompatible with reflow soldering.
2. If components will undergo multiple soldering processes, or other processes where the components may be subjected to intense heat, please check with Kingbright for compatibility.

CLEANING

1. Mild "no-clean" fluxes are recommended for use in soldering.
2. If cleaning is required, Kingbright recommends to wash components with water only. Do not use harsh organic solvents for cleaning, because they may damage the plastic parts. And the devices should not be washed for more than one minute.

CIRCUIT DESIGN NOTES

1. Protective current-limiting resistors may be necessary to operate the Displays.
2. LEDs mounted in parallel should each be placed in series with its own current-limiting resistor.



Detailed application notes are listed on our website.

http://www.kingbright.com/application_notes